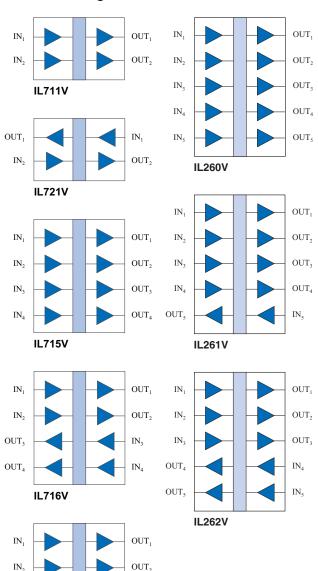


High Isolation Voltage Digital Isolators

Functional Diagrams



Features

- 4000 V_{RMS}/5660 V_{PK} isolation voltage (1 minute; per UL1577)
- 1000 V_{RMS}/1500 V_{DC} high voltage endurance
- High Temperature: -40°C to +125°C
- 50 kV/µs typ.; 30 kV/µs min. common mode transient immunity
- No carrier or clock for low EMI emissions and susceptibility
- 1.2 mA/channel typical quiescent current
- 100 ps typical pulse jitter
- 2 ns channel-to-channel skew
- 10 ns typical propagation delay
- 44000 year barrier life
- · Excellent magnetic immunity
- UL 1577 recognized; IEC 60747-5-5 (VDE 0884) certified
- True 8 mm creepage package

Applications

- · Board-to-board communication
- CANbus
- · Peripheral interfaces
- · Logic level shifting
- Equipment covered under IEC 61010-1 Edition 3
- 5 kV_{RMS} rated IEC 60601-1 medical applications

Description

NVE's IL200V/IL700V family of high isolation voltage digital isolators are CMOS devices manufactured with NVE's patented* IsoLoop® spintronic Giant Magnetoresistive (GMR) technology.

IL200/IL700 isolators are inherently low in EMI emissions with no carrier or clocks.

A unique ceramic/polymer composite barrier provides excellent isolation and virtually unlimited barrier life.

The parts use NVE's unique JEDEC-compliant 16 pin package with True 8 mm creepage under IEC 60601.

OUT.

 IN_4

IN₂

OUT.

IL717V



V-Series Isolators

Absolute Maximum Ratings

Parameters	Symbol	Min.	Тур.	Max.	Units	Test Conditions
Storage Temperature	$T_{\rm S}$	-55		150	°C	
Ambient Operating Temperature ⁽¹⁾	T_A	-40		125	°C	
Supply Voltage	V_{DD1}, V_{DD2}	-0.5		7	V	
Input Voltage	$V_{\rm I}$	-0.5		$V_{DD} + 0.5$	V	
Output Voltage	V_{0}	-0.5		$V_{DD} + 0.5$	V	
Output Current Drive	I_{o}			10	mA	
Lead Solder Temperature				260	°C	10 sec.
ESD			2		kV	HBM

Recommended Operating Conditions

to commonwear a per at mig e com	3						
Parameters	Symbol	Min.	Тур.	Max.	Units	Test Conditions	
Ambient Operating Temperature	T_A	-40		125	°C		
Supply Voltage	$V_{\mathrm{DD1}},V_{\mathrm{DD2}}$	3.0		5.5	V		
Logic High Input Voltage	V_{IH}	2.4		$V_{\scriptscriptstyle m DD}$	V		
Logic Low Input Voltage	$V_{\scriptscriptstyle IL}$	0		0.8	V		
Input Signal Rise and Fall Times	$t_{\rm IR},t_{\rm IF}$			1	μs		

Insulation Specifications

Parameters		Symbol	Min.	Тур.	Max.	Units	Test Conditions
Creepage Distance (external)			8.03	8.3		mm	Per IEC 60601
Total Barrier Thickness (intern	nal)		0.012	0.013		mm	
Leakage Current ⁽⁵⁾				0.2		μΑ	$240 \text{ V}_{\text{RMS}}, 60 \text{ Hz}$
Barrier Resistance ⁽⁵⁾		R_{IO}		>10 ¹⁴		Ω	500 V
Barrier Capacitance ⁽⁵⁾		C_{10}		2		pF	f = 1 MHz
Comparative Tracking Index		CTI	≥175			V	Per IEC 60112
High Voltage Endurance (Maximum Barrier Voltage for Indefinite Life)	AC DC	V_{IO}	1000 1500			$V_{ m RMS}$ $V_{ m DC}$	At maximum operating temperature
Barrier Life	_			44000		Years	100°C, 1000 V _{RMS} , 60% CL activation energy

Package Characteristics

a delago offaración lotro						
Parameters	Symbol	Min.	Тур.	Max.	Units	Test Conditions
Thermal Resistance			28		°C/W	Thermocouple at center underside of package
Package Power Dissipation	P _{PD}			150	mW	$f = 1 \text{ MHz}, V_{DD} = 5 \text{ V}$





Safety and Approvals

IEC 60747-5-5 (VDE 0884) (File Number 5016933-4880-0001)

- Working Voltage (V_{IORM}) 600 V_{RMS} (848 V_{PK}); basic insulation; pollution degree 2
- Transient overvoltage (V_{IOTM}) and surge voltage (V_{IOSM}) 4000 V_{PK}
- Each part tested at 1590 V_{PK} for 1 second, 5 pC partial discharge limit
- \bullet Samples tested at 4000 V_{PK} for 60 sec.; then 1358 V_{PK} for 10 sec. with 5 pC partial discharge limit

IEC 61010-1 (Edition 2; TUV Certificate Numbers N1502812; N1502812-101)

Reinforced Insulation; Pollution Degree II; Material Group III

Package	Working Voltage
Wide-body SOIC/True 8 TM	$300 \mathrm{V}_{\mathrm{RMS}}$

UL 1577 (Component Recognition Program File Number E207481)

4000 V_{RMS}/5660 V_{PK} isolation voltage

Each part tested at 4800 V_{RMS} (6800 V_{PK}) for 1 second; each lot sample tested at 4000 V_{RMS} (5660 V_{PK}) for 1 minute

Soldering Profile

Per JEDEC J-STD-020C, MSL 1





IL711V Pin Connections

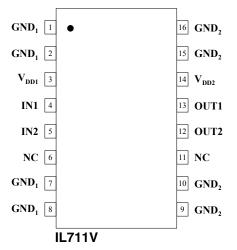
1	GND_1	Ground return for V _{DD1}
2	GND	(pins 1, 2, 7, and 8 internally connected)
3	V_{DD1}	Supply voltage
4	IN_1	Data in, channel 1
5	IN_2	Data in, channel 2
6	NC	No connection
7	GND ₁	Ground return for V _{DD1}
8	GND_1	(pins 1, 2, 7, and 8 internally connected)
9	GND ₂	Ground return for V _{DD2}
10	OND_2	(pins 9, 10, 15, and 16 internally connected)
11	NC	No connection
12	OUT_2	Data out, channel 2
13	OUT ₁	Data out, channel 1
14	V_{DD2}	Supply voltage
15	GND ₂	Ground return for V _{DD2}
16	OND_2	(pins 9, 10, 15, and 16 internally connected)

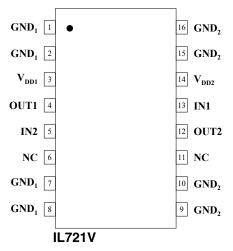
IL721V Pin Connections

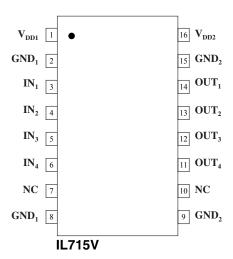
	V I III C	Officelions
1	GND ₁	Ground return for V _{DD1}
2	GND_1	(pins 1, 2, 7, and 8 internally connected)
3	V_{DD1}	Supply voltage
4	OUT_1	Data out, channel 1
5	IN_2	Data in, channel 2
6	NC	No connection
7	GND ₁	Ground return for V _{DD1}
8	GND ₁	(pins 1, 2, 7, and 8 internally connected)
9	GND_2	Ground return for V _{DD2}
10	GND_2	(pins 9, 10, 15, and 16 internally connected)
11	NC	No connection
12	OUT_2	Data out, channel 2
13	IN_1	Data in, channel 1
14	V_{DD2}	Supply voltage
15	GND ₂	Ground return for V _{DD2}
16	GND_2	(pins 9, 10, 15, and 16 internally connected)

IL715V Pin Connections

1	V_{DD1}	Supply voltage
2	GND_1	Ground return for V _{DD1} *
3	IN_1	Data in, channel 1
4	IN_2	Data in, channel 2
5	IN_3	Data in, channel 3
6	IN_4	Data in, channel 4
7	NC	No connection
8	GND_1	Ground return for V _{DD1} *
9	GND_2	Ground return for V _{DD2} *
10	NC	No connection
11	OUT ₄	Data out, channel 4
12	OUT ₃	Data out, channel 3
13	OUT ₂	Data out, channel 2
14	OUT ₁	Data out, channel 1
15	GND_2	Ground return for V _{DD2} *
16	V_{DD2}	Supply voltage





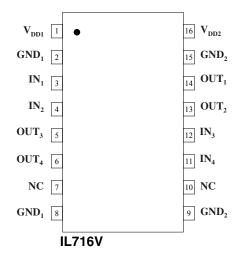






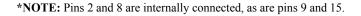
IL716V Pin Connections

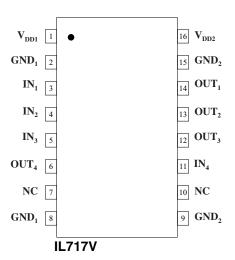
1	V_{DD1}	Supply voltage
2	GND_1	Ground Return for V _{DD1} *
3	IN_1	Data in, channel 1
4	IN_2	Data in, channel 2
5	OUT ₃	Data out, channel 3
6	OUT_4	Data out, channel 4
7	NC	No connection
8	GND_1	Ground Return for V _{DD1} *
9	GND_2	Ground Return for V _{DD2} *
10	NC	No connection
11	IN_4	Data in, channel 4
12	IN_3	Data in, channel 3
13	OUT ₂	Data out, channel 2
14	OUT_1	Data out, channel 1
15	GND_2	Ground Return for V _{DD2} *
16	V_{DD2}	Supply voltage



IL717V Pin Connections

1	V_{DD1}	Supply voltage
2	GND_1	Ground return for V _{DD1} *
3	IN_1	Data in, channel 1
4	IN_2	Data in, channel 2
5	IN_3	Data in, channel 3
6	OUT ₄	Data out, channel 4
7	NC	No connection
8	GND_1	Ground return for V _{DD1} *
9	GND_2	Ground return for V _{DD2} *
10	NC	No connection
11	IN_4	Data in, channel 4
12	OUT ₃	Data out, channel 3
13	OUT ₂	Data out, channel 2
14	OUT_1	Data out, channel 1
15	GND ₂	Ground return for V _{DD2} *
16	V_{DD2}	Supply voltage





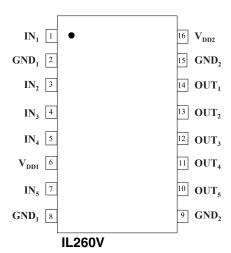
^{*}NOTE: Pins 2 and 8 are internally connected, as are pins 9 and 15.





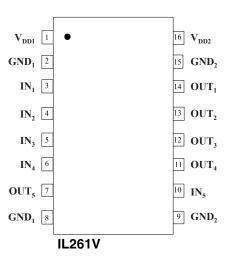
IL260V Pin Connections

1	IN_1	Input 1
2	GND_1	Ground*
3	IN_2	Input 2
4	IN_3	Input 3
5	IN_4	Input 4
6	V_{DD1}	Supply Voltage 1
7	IN_5	Input 5
8	GND_1	Ground*
9	GND_2	Ground*
10	OUT_5	Output 5
11	OUT_4	Output 4
12	OUT ₃	Output 3
13	OUT_2	Output 2
14	OUT ₁	Output 1
15	GND_2	Ground*
16	V_{DD2}	Supply Voltage 2
	. DD2	~~rr-/ · · · · · · · · · ·



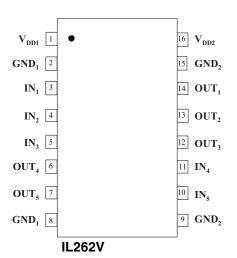
IL261V Pin Connections

1	V_{DD1}	Supply Voltage 1
2	GND_1	Ground*
3	IN_1	Input 1
4	IN_2	Input 2
5	IN_3	Input 3
6	IN_4	Input 4
7	OUT ₅	Output 5
8	GND_1	Ground*
9	GND_2	Ground*
10	IN_5	Input 5
11	OUT_4	Output 4
12	OUT ₃	Output 3
13	OUT ₂	Output 2
14	OUT_1	Output 1
15	GND_2	Ground*
16	V_{DD2}	Supply Voltage 2



IL262V Pin Connections

1	V_{DD1}	Supply Voltage 1			
2	GND_1	Ground*			
3	IN_1	Input 1			
4	IN_2	Input 2			
5	IN_3	Input 3			
6	OUT_4	Output 4			
7	OUT_5	Output 5			
8	GND_1	Ground*			
9	GND_2	Ground*			
10	IN_5	Input 5			
11	IN_4	Input 4			
12	OUT_3	Output 3			
13	OUT ₂	Output 2			
14	OUT_1	Output 1			
15	GND_2	Ground*			
16	V_{DD2}	Supply Voltage 2			



^{*}NOTE: Pins 2 and 8 are internally connected, as are pins 9 and 15.





3.3 Volt Electrical Specifications (T_{min} to T_{max} unless otherwise stated)									
Parameters	Symbol	Min.	Тур.	Max.	Units	Test Conditions			
Input Quiescent Supply Current									
IL260V			300	400	μΑ				
IL261V			1.2	1.75	mA				
IL262V			2.4	3.5	mA				
IL711V	ī		8	10	μΑ				
IL721V	I_{DD1}		1.2	1.75	mA				
IL715V			16	20	μΑ				
IL716V			2.4	3.5	mA				
IL717V			1.2	1.75	mA				
Output Quiescent Supply Current	Output Quiescent Supply Current								
IL260V			6	8.75	mA				
IL261V			4.8	7	mA				
IL262V			4.8	7	mA				
IL711V	ī		2.4	3.5	mA				
IL721V	I_{DD2}		1.2	1.75	mA				
IL715V			4.8	7	mA				
IL716V			2.4	3.5	mA				
IL717V			3.6	5.25	mA				
Logic Input Current	$I_{\rm I}$	-10		10	μΑ				
Logic High Output Voltage	V_{OH}	$V_{DD} - 0.1$ 0.8 x V_{DD}	$V_{\rm DD}$ 0.9 x $V_{\rm DD}$		V	$I_O = -20 \mu A, V_I = V_{IH}$ $I_O = -4 \text{ mA}, V_I = V_{IH}$			
Logic Low Output Voltage	V_{OL}		0 0.5	0.1 0.8	V	$I_O = 20 \mu A, V_I = V_{IL}$ $I_O = 4 \text{ mA}, V_I = V_{IL}$			

Switching Specifications ($V_{DD} = 3.3 \text{ V}$)							
Maximum Data Rate		100	110		Mbps	$C_L = 15 \text{ pF}$	
Pulse Width ⁽⁷⁾	PW	10	7.5		ns	50% Points, V _o	
Propagation Delay Input to Output (High to Low)	$t_{ m PHL}$		12	18	ns	$C_L = 15 \text{ pF}$	
Propagation Delay Input to Output (Low to High)	$t_{\rm PLH}$		12	18	ns	$C_L = 15 \text{ pF}$	
Pulse Width Distortion ⁽²⁾	PWD		2	3	ns	$C_L = 15 \text{ pF}$	
Propagation Delay Skew ⁽³⁾	t_{PSK}		4	6	ns	$C_L = 15 \text{ pF}$	
Output Rise Time (10%–90%)	t_{R}		2	4	ns	$C_L = 15 \text{ pF}$	
Output Fall Time (10%–90%)	t_{F}		2	4	ns	$C_L = 15 \text{ pF}$	
Common Mode Transient Immunity	$ CM_H , CM_L $	30	50		kV/µs	$V_{CM} = 1500 V_{DC}$	
(Output Logic High or Logic Low) ⁽⁴⁾	CIVI _H , CIVI _L	50	30		Κνημο	$t_{\text{TRANSIENT}} = 25 \text{ ns}$	
Channel-to-Channel Skew	t_{CSK}	•	2	3	ns	$C_L = 15 \text{ pF}$	
Dynamic Power Consumption ⁽⁶⁾		•	140	240	μA/Mbps	per channel	

Magnetic Field Immunity ⁽⁸⁾ (V _{DD2} = 3V, 3V <v<sub>DD1<5.5V)</v<sub>							
Power Frequency Magnetic Immunity H_{PF} 1000 1500 A/m 50Hz/60Hz						50Hz/60Hz	
Pulse Magnetic Field Immunity	H_{PM}	1800	2000		A/m	$t_p = 8\mu s$	
Damped Oscillatory Magnetic Field	H_{OSC}	1800	2000		A/m	0.1Hz – 1MHz	
Cross-axis Immunity Multiplier ⁽⁹⁾	K_{X}		2.5				





5 Volt Electrical Specifications (T_{min} to T_{max} unless otherwise stated)									
Parameters	Symbol	Min.	Тур.	Max.	Units	Test Conditions			
Input Quiescent Supply Current									
IL260V			350	500	μΑ				
IL261V			1.8	2.5	mA				
IL262V			3.6	5	mA				
IL711V	ī		10	15	μΑ				
IL721V	I_{DD1}		1.8	2.5	mA				
IL715V			20	15	μΑ				
IL716V			3.6	5	mA				
IL717V			1.8	2.5	mA				
Output Quiescent Supply Current									
IL260V			9	12.5	mA				
IL261V			7.2	10	mA				
IL262V			7.2	10	mA				
IL711V	Ţ		3.6	5	mA				
IL721V	I_{DD2}		1.8	2.5	mA				
IL715V			3.6	5	mA				
IL716V			3.6	5	mA				
IL717V			5.4	7.5	mA				
Logic Input Current	$I_{\rm I}$	-10		10	μΑ				
Logic High Output Voltage	V_{OH}	$V_{DD} - 0.1$	V _{DD}		V	$I_{O} = -20 \mu A, V_{I} = V_{IH}$			
		$0.8 \times V_{DD}$	$0.9 \times V_{DD}$	0.1		$I_O = -4 \text{ mA}, V_I = V_{IH}$			
Logic Low Output Voltage	V_{OL}		0	0.1	V	$I_{O} = 20 \mu A, V_{I} = V_{IL}$			
			0.5	0.8		$I_O = 4 \text{ mA}, V_I = V_{IL}$			

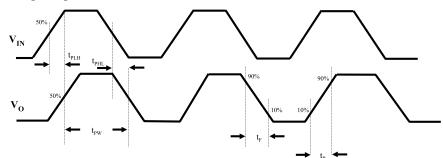
Switching Specifications ($V_{DD} = 5 \text{ V}$)							
Maximum Data Rate		100	110		Mbps	$C_L = 15 \text{ pF}$	
Pulse Width ⁽⁷⁾	PW	10	7.5		ns	50% Points, V _o	
Propagation Delay Input to Output (High to Low)	$t_{ m PHL}$		10	15	ns	$C_L = 15 \text{ pF}$	
Propagation Delay Input to Output (Low to High)	t _{PLH}		10	15	ns	$C_L = 15 \text{ pF}$	
Pulse Width Distortion ⁽²⁾	PWD		2	3	ns	$C_L = 15 \text{ pF}$	
Pulse Jitter ⁽¹⁰⁾	$t_{ m J}$		100		ps	$C_L = 15 \text{ pF}$	
Propagation Delay Skew ⁽³⁾	t_{PSK}		4	6	ns	$C_L = 15 \text{ pF}$	
Output Rise Time (10%–90%)	t_{R}		1	3	ns	$C_L = 15 \text{ pF}$	
Output Fall Time (10%–90%)	t_{F}		1	3	ns	$C_L = 15 \text{ pF}$	
Common Mode Transient Immunity (Output Logic High or Logic Low) ⁽⁴⁾	$ CM_H , CM_L $	30	50		kV/μs	$V_{CM} = 1500 V_{DC}$ $t_{TRANSIENT} = 25 \text{ ns}$	
Channel to Channel Skew	$t_{\rm CSK}$		2	3	ns	$C_L = 15 \text{ pF}$	
Dynamic Power Consumption ⁽⁶⁾			200	340	μA/Mbps	per channel	





Magnetic Field Immunity ⁽⁸⁾ (V _{DD2} = 5V, 3V <v<sub>DD1<5.5V)</v<sub>							
Power Frequency Magnetic Immunity	H_{PF}	2800	3500		A/m	50Hz/60Hz	
Pulse Magnetic Field Immunity	H_{PM}	4000	4500		A/m	$t_p = 8\mu s$	
Damped Oscillatory Magnetic Field	H_{OSC}	4000	4500		A/m	0.1Hz – 1MHz	
Cross-axis Immunity Multiplier ⁽⁹⁾	K_X		2.5				

Timing Diagram



	Legena								
t _{PLH} Propagation Delay, Low to High									
	t _{PHL} Propagation Delay, High to Low								
	$t_{\scriptscriptstyle \mathrm{PW}}$	Minimum Pulse Width							
	t_{R}	Rise Time							
	$t_{\scriptscriptstyle F}$	Fall Time							

Notes (apply to both 3.3 V and 5 V specifications):

- Absolute maximum ambient operating temperature means the device will not be damaged if operated under these conditions. It does not guarantee performance.
- 2. PWD is defined as $|t_{PHL} - t_{PLH}|$. %PWD is equal to PWD divided by pulse width.
- t_{PSK} is the magnitude of the worst-case difference in t_{PHL} and/or t_{PLH} between devices at 25°C.
- CM_H is the maximum common mode voltage slew rate that can be sustained while maintaining $V_O > 0.8 \ V_{DD2}$. CM_L is the maximum common mode input voltage that can be sustained while maintaining $V_0 < 0.8$ V. The common mode voltage slew rates apply to both rising and falling common mode voltage edges.
- 5. Device is considered a two terminal device: pins 1–4 shorted and pins 5–8 shorted.
- Dynamic power consumption is calculated per channel and is supplied by the channel's input side power supply.
- Minimum pulse width is the minimum value at which specified PWD is guaranteed.
- The relevant test and measurement methods are given in the Electromagnetic Compatibility section on p. 6. 8.
- External magnetic field immunity is improved by this factor if the field direction is "end-to-end" rather than to "pin-to-pin" (see diagram on p. 6).
- 10. 64k-bit pseudo-random binary signal (PRBS) NRZ bit pattern with no more than five consecutive 1s or 0s; 800 ps transition time.





Application Information

Electrostatic Discharge Sensitivity

This product has been tested for electrostatic sensitivity to the limits stated in the specifications. However, NVE recommends that all integrated circuits be handled with appropriate care to avoid damage. Damage caused by inappropriate handling or storage could range from performance degradation to complete failure.

Electromagnetic Compatibility

IsoLoop Isolators have the lowest EMC footprint of any isolation technology. IsoLoop Isolators' Wheatstone bridge configuration and differential magnetic field signaling ensure excellent EMC performance against all relevant standards.

These isolators are fully compliant with generic EMC standards EN50081, EN50082-1 and the umbrella line-voltage standard for Information Technology Equipment (ITE) EN61000. NVE has completed compliance tests in the categories below:

EN50081-1

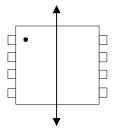
Residential, Commercial & Light Industrial Methods EN55022, EN55014

EN50082-2: Industrial Environment

Methods EN61000-4-2 (ESD), EN61000-4-3 (Electromagnetic Field Immunity), EN61000-4-4 (Electrical Transient Immunity), EN61000-4-6 (RFI Immunity), EN61000-4-8 (Power Frequency Magnetic Field Immunity), EN61000-4-9 (Pulsed Magnetic Field), EN61000-4-10 (Damped Oscillatory Magnetic Field) ENV50204

Radiated Field from Digital Telephones (Immunity Test)

Immunity to external magnetic fields is even higher if the field direction is "end-to-end" rather than to "pin-to-pin" as shown in the diagram below:



Cross-axis Field Direction

Dynamic Power Consumption

IsoLoop Isolators achieve their low power consumption from the way they transmit data across the isolation barrier. By detecting the edge transitions of the input logic signal and converting these to narrow current pulses, a magnetic field is created around the GMR Wheatstone bridge. Depending on the direction of the magnetic field, the bridge causes the output comparator to switch following the input logic signal. Since the current pulses are narrow, about 2.5 ns, the power consumption is independent of mark-to-space ratio and solely dependent on frequency. This has obvious advantages over optocouplers, which have power consumption heavily dependent on mark-to-space ratio.

Power Supply Decoupling

Both power supplies to these devices should be decoupled with low-ESR 47 nF ceramic capacitors. Ground planes for both GND₁ and GND₂ are highly recommended for data rates above 10 Mbps. Capacitors must be located as close as possible to the V_{DD} pins.

Maintaining Creepage

Creepage distances are often critical in isolated circuits. In addition to meeting JEDEC standards, NVE isolator packages have unique creepage specifications. Standard pad libraries often extend under the package, compromising creepage and clearance. Similarly, ground planes, if used, should be spaced to avoid compromising clearance. The package drawing and recommended pad layout are included in this datasheet.

Signal Status on Start-up and Shut Down

To minimize power dissipation, input signals are differentiated and then latched on the output side of the isolation barrier to reconstruct the signal. This could result in an ambiguous output state depending on power up, shutdown and power loss sequencing. Unless the circuit connected to the isolator performs its own power- on reset (POR), a start-up initialization circuit should be considered. Initialization consists of toggling the input either high then low, or low then high.

In CAN applications, the IL721V should be used with CAN transceivers with Dominant Timeout functions for seamless POR. Most CAN transceivers have Dominant Timeout options. Examples include NXP's TJA 1050 and TJA 1040 transceivers.

IEC 60601-1 Compliance

IEC 60601 specifies isolator creepage for medical safety, and is also used for demanding non-medical applications. Requirements are summarized as follows:

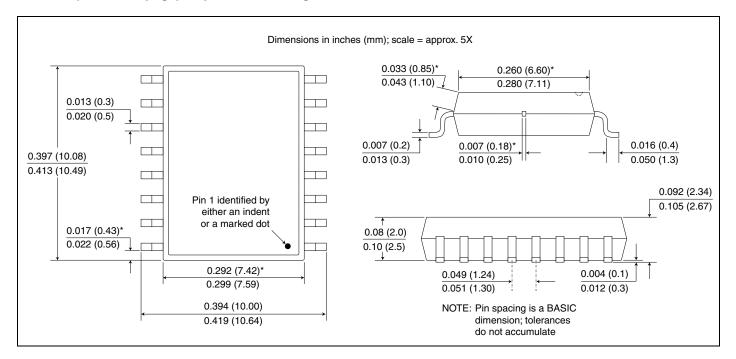
	Working Voltage (V _{RMS})			
	Insulation	125	250	
Croopaga (mm)	Single	3.0	4.0	
Creepage (mm)	Double	6.0	8.0	
Dielectric strength	Single	2000	2500	
Dielectric strength	Double	3000	4000	

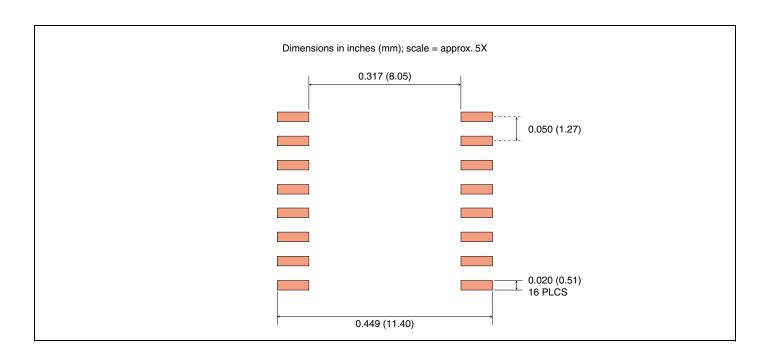
With 4000 V isolation and true 8 millimeter creepage, V-Series Isolators allow IEC 60601-1 compliance for 120V and 220/240V applications.





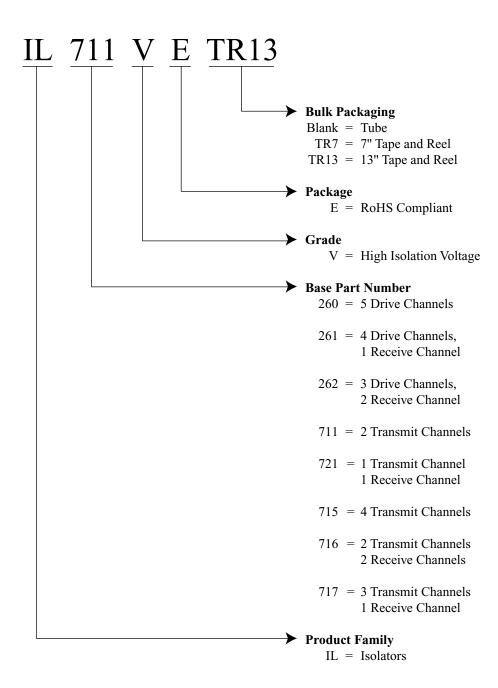
True 8[™] (8 mm creepage) 16-pin SOIC Package







Ordering Information



RoHS COMPLIANT





ISB-DS-001-IL700V-C November 2013

ISB-DS-001-IL700V-B September 2013

ISB-DS-001-IL700V-A August 2013

ISB-DS-001-IL711/21V-PRELIM June 2013

ISB-DS-001-IL711/21V-PRELIM May 2013

Changes

- IEC 60747-5-5 (VDE 0884) certification.
- Added IEC 60601 compliance table.
- Upgraded from MSL 2 to MSL 1.

Changes

- Added five-channel part types (IL260V/IL261V/IL262V).
- UL 1577 recognized.

Changes

- Added four-channel part types (IL715V/IL716V/IL717V)
- Tightened quiescent current specifications.

Changes

Increased transient immunity specifications based on additional data.

Changes

- Increased transient immunity specifications based on additional data.
- Defined IL711V and IL721V (V-Series high isolation voltage).
- Updated package drawings.
- Added recommended solder pad layouts.





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November 2013